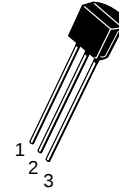
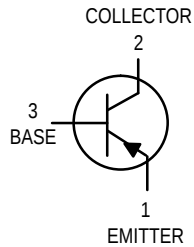


**BF421
BF423**

**CASE 29-11, STYLE 14
TO-92 (TO-226AA)**
MAXIMUM RATINGS

Rating	Symbol	BF421	BF423	Unit
Collector–Emitter Voltage	V_{CEO}	–300	–250	Vdc
Collector–Base Voltage	V_{CBO}	–300	–250	Vdc
Emitter–Base Voltage	V_{EBO}	–5.0		Vdc
Collector Current — Continuous	I_C	–500		mAdc
Total Device Dissipation @ $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	625 5.0		mW mW/°C
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	1.5 12		Watts mW/°C
Operating and Storage Junction Temperature Range	T_J, T_{stg}	–55 to +150		°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	200	°C/W
Thermal Resistance, Junction to Case	$R_{\theta JC}$	83.3	°C/W

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
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OFF CHARACTERISTICS

Collector–Emitter Breakdown Voltage (1) ($I_C = -1.0 \text{ mAdc}$, $I_E = 0$)	BF421 BF423	$V_{(BR)CEO}$	–300 –250	— —	Vdc
Collector–Base Breakdown Voltage ($I_C = -100 \mu\text{Adc}$, $I_E = 0$)	BF421 BF423	$V_{(BR)CBO}$	–300 –250	— —	Vdc
Emitter–Base Breakdown Voltage ($I_E = -100 \mu\text{Adc}$, $I_C = 0$)	BF421 BF423	$V_{(BR)EBO}$	–5.0 –5.0	— —	Vdc
Collector Cutoff Current ($V_{CB} = -200 \text{ Vdc}$, $I_E = 0$)	BF421 BF423	I_{CBO}	— —	–0.01 —	μAdc
Emitter Cutoff Current ($V_{EB} = -5.0 \text{ Vdc}$, $I_C = 0$)	BF421 BF423	I_{EBO}	— —	–100 —	nAdc

1. Pulse Test: Pulse Width $\leq 300 \mu\text{s}$; Duty Cycle $\leq 2.0\%$.

BF421 BF423**ELECTRICAL CHARACTERISTICS** ($T_A = 25^\circ\text{C}$ unless otherwise noted) (Continued)

Characteristic	Symbol	Min	Max	Unit
ON CHARACTERISTICS				
DC Current Gain ($I_C = -25\text{ mA}$, $V_{CE} = -20\text{ Vdc}$)	h_{FE}	50	—	—
		50	—	
Collector–Emitter Saturation Voltage ($I_C = -20\text{ mAdc}$, $I_B = -2.0\text{ mAdc}$)	$V_{CE(sat)}$	—	–0.5	Vdc
Base–Emitter Saturation Voltage ($I_C = -20\text{ mA}$, $I_B = -2.0\text{ mA}$)	$V_{BE(sat)}$	—	–2.0	Vdc
SMALL–SIGNAL CHARACTERISTICS				
Current–Gain — Bandwidth Product ($I_C = -10\text{ mAdc}$, $V_{CE} = -10\text{ Vdc}$, $f = 20\text{ MHz}$)	f_T	60	—	MHz
Common Emitter Feedback Capacitance ($V_{CB} = -30\text{ Vdc}$, $I_E = 0$, $f = 1.0\text{ MHz}$)	C_{re}	—	2.8	pF

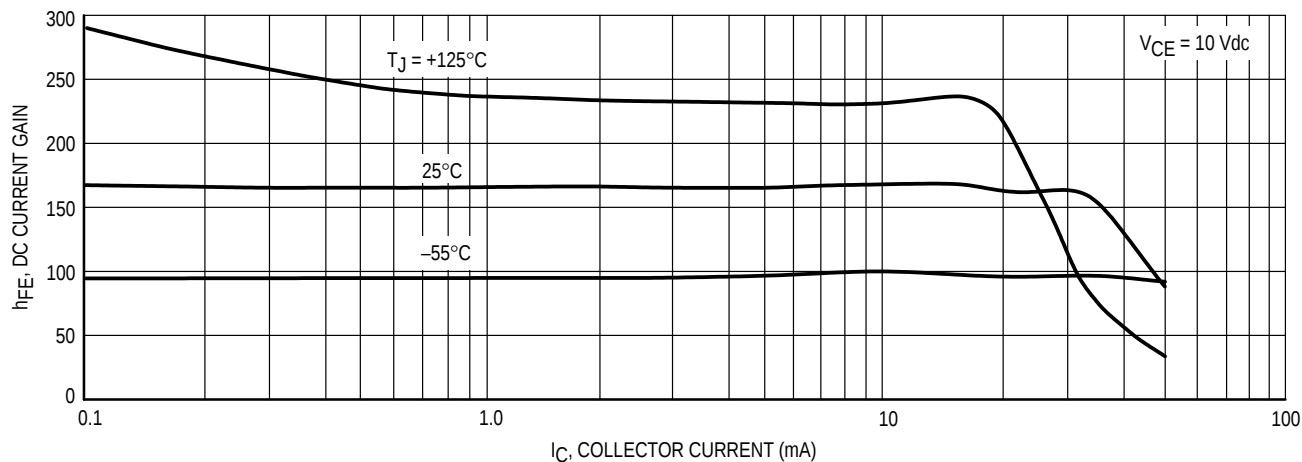


Figure 1. DC Current Gain

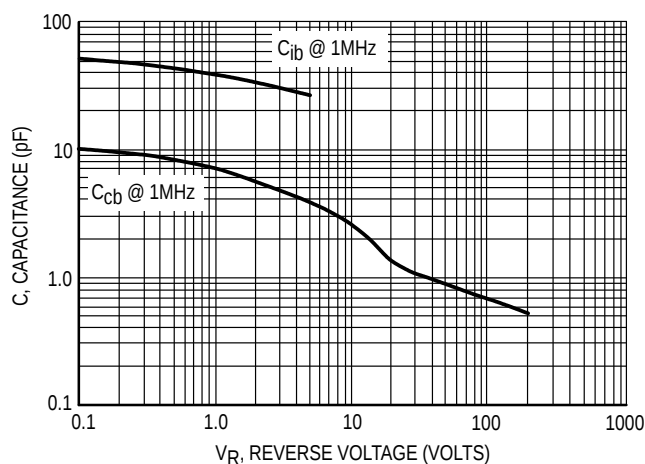


Figure 2. Capacitance

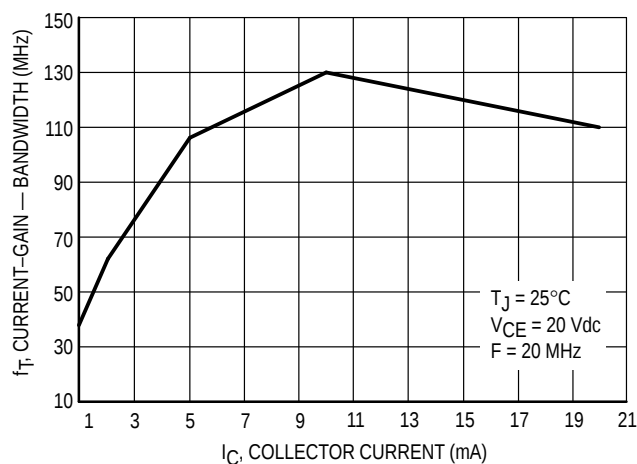


Figure 3. Current-Gain — Bandwidth

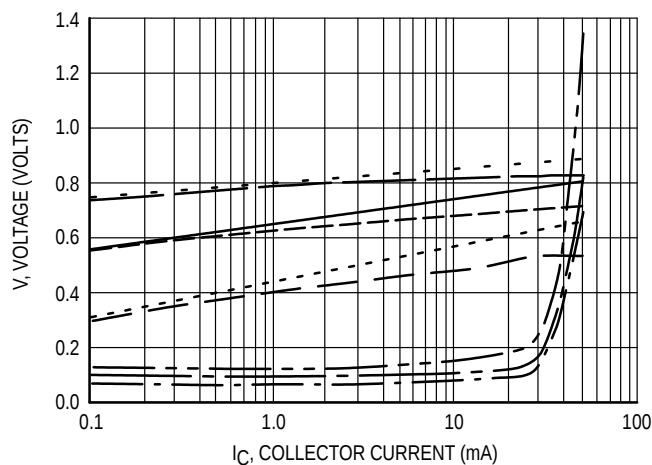
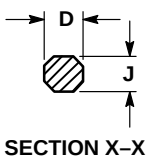
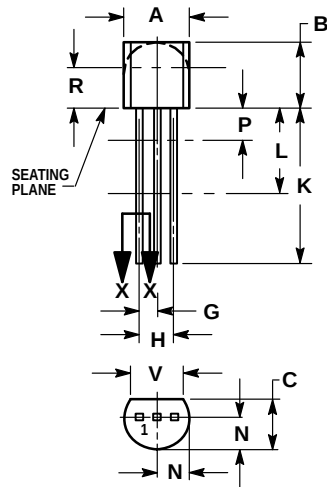


Figure 4. "ON" Voltages

PACKAGE DIMENSIONS



CASE 029-11
(TO-226AA)
ISSUE AJ

- NOTES:
- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 - 2. CONTROLLING DIMENSION: INCH.
 - 3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
 - 4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.175	0.205	4.45	5.20
B	0.170	0.210	4.32	5.33
C	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
E	0.045	0.055	1.15	1.39
F	0.095	0.105	2.42	2.66
G	0.015	0.020	0.39	0.50
H	0.500	—	12.70	—
J	0.250	—	6.35	—
K	0.080	0.105	2.04	2.66
L	—	0.100	—	2.54
N	0.115	—	2.93	—
P	0.135	—	3.43	—

STYLE 14:
PIN 1. EMITTER
2. COLLECTOR
3. BASE

